

1. Features

- **Low-voltage and Standard-voltage Operation**
 - 2.7 (V_{CC} = 2.7V to 5.5V)
 - 1.8 (V_{CC} = 1.8V to 5.5V)
- **Three-wire Serial Interface**
- **2 MHz Clock Rate (5V) Compatibility**
- **Self-timed Write Cycle (10 ms max)**
- **High Reliability**
 - Endurance: 1 Million Write Cycles
 - Data Retention: 100 Years
- **Automotive Grade, Extended Temperature, and Lead-free/Halogen-free Devices Available**
- **8-lead PDIP, 8-lead JEDEC SOIC, and 8-lead TSSOP Packages**

2. Description

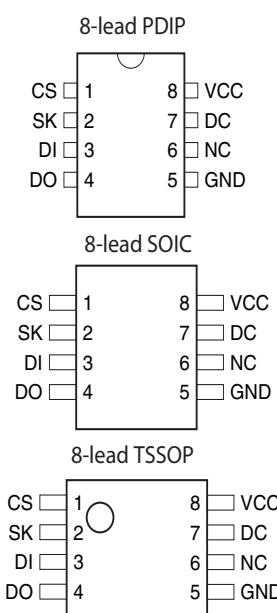
The AT93C46A provides 1024 bits of serial electrically-erasable programmable read-only memory (EEPROM) organized as 64 words of 16 bits each. The device is optimized for use in many industrial and commercial applications where low-power and low-voltage operation are essential. The AT93C46A is available in space-saving 8-lead PDIP, 8-lead JEDEC SOIC, and 8-lead TSSOP packages.

The AT93C46A is enabled through the Chip Select pin (CS) and accessed via a three-wire serial interface consisting of Data Input (DI), Data Output (DO), and Shift Clock (SK). Upon receiving a Read instruction at DI, the address is decoded and the data is clocked out serially on the data output DO pin. The write cycle is completely self-timed and no separate erase cycle is required before write. The write cycle is only enabled when the part is in the erase/write enable state. When CS is brought high following the initiation of a write cycle, the DO pin outputs the ready/busy status of the part.

The AT93C46A is available in 2.7V to 5.5V and 1.8V to 5.5V versions.

Table 2-1. Pin Configuration

Pin Name	Function
CS	Chip Select
SK	Serial Data Clock
DI	Serial Data Input
DO	Serial Data Output
GND	Ground
VCC	Power Supply



Three-wire Serial EEPROM 1K (64 x 16)

AT93C46A

Note: Not recommended for new design; please refer to AT93C46E datasheet.

Absolute Maximum Ratings*

Operating Temperature.....	-55°C to +125°C
Storage Temperature	-65°C to +150°C
Voltage on Any Pin with Respect to Ground	-1.0V to +7.0V
Maximum Operating Voltage	6.25V
DC Output Current.....	5.0 mA

*NOTICE: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Figure 2-1. Block Diagram

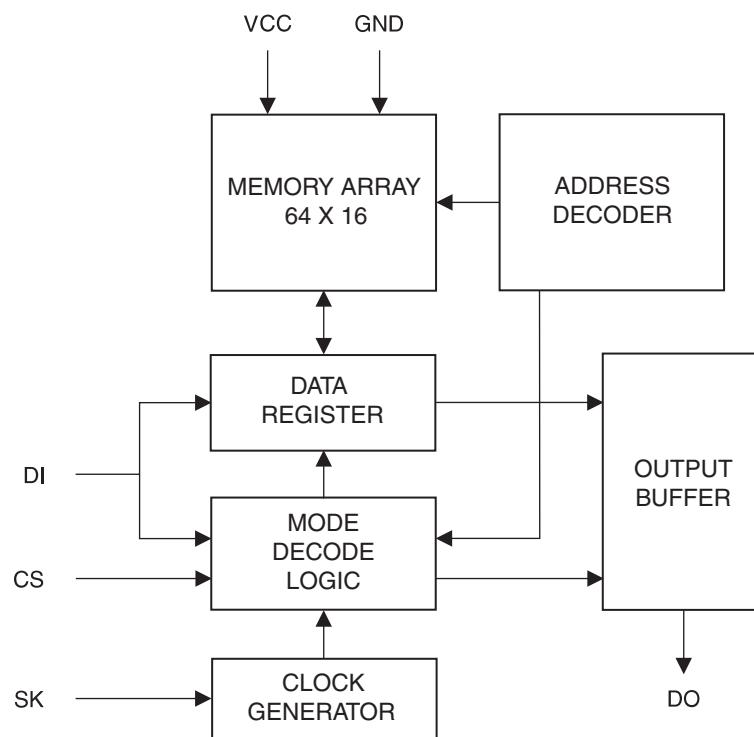


Table 2-2. Pin Capacitance⁽¹⁾

Applicable over recommended operating range from $T_A = 25^\circ\text{C}$, $f = 1.0 \text{ MHz}$, $V_{CC} = +5.0\text{V}$ (unless otherwise noted)

Symbol	Test Conditions	Max	Units	Conditions
C_{OUT}	Output Capacitance (DO)	5	pF	$V_{OUT} = 0\text{V}$
C_{IN}	Input Capacitance (CS, SK, DI)	5	pF	$V_{IN} = 0\text{V}$

Note: This parameter is characterized and is not 100% tested.

Table 2-3. DC CharacteristicsApplicable over recommended operating range from: $T_{AI} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = +1.8\text{V}$ to $+5.5\text{V}$ (unless otherwise noted)

Symbol	Parameter	Test Condition		Min	Typ	Max	Unit
V_{CC1}	Supply Voltage			1.8		5.5	V
V_{CC2}	Supply Voltage			2.7		5.5	V
V_{CC3}	Supply Voltage			4.5		5.5	V
I_{CC}	Supply Current	$V_{CC} = 5.0\text{V}$	READ at 1.0 MHz		0.5	2.0	mA
			WRITE at 1.0 MHz		0.5	2.0	mA
I_{SB1}	Standby Current	$V_{CC} = 1.8\text{V}$	CS = 0V		0.4	1.0	μA
I_{SB2}	Standby Current	$V_{CC} = 2.7\text{V}$	CS = 0V		6.0	10.0	μA
I_{SB3}	Standby Current	$V_{CC} = 5.0\text{V}$	CS = 0V		10.0	15.0	μA
I_{IL}	Input Leakage	$V_{IN} = 0\text{V}$ to V_{CC}			0.1	1.0	μA
I_{OL}	Output Leakage	$V_{IN} = 0\text{V}$ to V_{CC}			0.1	1.0	μA
$V_{IL1}^{(1)}$	Input Low Voltage	$2.7\text{V} \leq V_{CC} \leq 5.5\text{V}$		-0.6		0.8	V
$V_{IH1}^{(1)}$	Input High Voltage			2.0		$V_{CC} + 1$	
$V_{IL2}^{(1)}$	Input Low Voltage	$1.8\text{V} \leq V_{CC} \leq 2.7\text{V}$		-0.6		$V_{CC} \times 0.3$	V
$V_{IH2}^{(1)}$	Input High Voltage			$V_{CC} \times 0.7$		$V_{CC} + 1$	
V_{OL1}	Output Low Voltage	$2.7\text{V} \leq V_{CC} \leq 5.5\text{V}$	$I_{OL} = 2.1\text{ mA}$			0.4	V
V_{OH1}	Output High Voltage		$I_{OH} = -0.4\text{ mA}$	2.4			V

Note: 1. V_{IL} min and V_{IH} max are reference only and are not tested.

Table 2-4. AC Characteristics

Applicable over recommended operating range from $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$, $V_{CC} = +2.5\text{V}$ to $+5.5\text{V}$, $CL = 1 \text{ TTL Gate}$ and 100 pF (unless otherwise noted)

Symbol	Parameter	Test Condition		Min	Typ	Max	Units
f_{SK}	SK Clock Frequency	4.5V $\leq V_{CC} \leq 5.5\text{V}$		0		2	
		2.7V $\leq V_{CC} \leq 5.5\text{V}$		0		1	
		1.8V $\leq V_{CC} \leq 5.5\text{V}$		0		0.25	
t_{SKH}	SK High Time	4.5V $\leq V_{CC} \leq 5.5\text{V}$		250			
		2.7V $\leq V_{CC} \leq 5.5\text{V}$		250			
		1.8V $\leq V_{CC} \leq 5.5\text{V}$		1000			ns
t_{SKL}	SK Low Time	4.5V $\leq V_{CC} \leq 5.5\text{V}$		250			
		2.7V $\leq V_{CC} \leq 5.5\text{V}$		250			
		1.8V $\leq V_{CC} \leq 5.5\text{V}$		1000			ns
t_{CS}	Minimum CS Low Time	4.5V $\leq V_{CC} \leq 5.5\text{V}$		250			
		2.7V $\leq V_{CC} \leq 5.5\text{V}$		250			
		1.8V $\leq V_{CC} \leq 5.5\text{V}$		1000			ns
t_{CSS}	CS Setup Time	Relative to SK	4.5V $\leq V_{CC} \leq 5.5\text{V}$	50			
			2.7V $\leq V_{CC} \leq 5.5\text{V}$	50			
			1.8V $\leq V_{CC} \leq 5.5\text{V}$	200			ns
t_{DIS}	DI Setup Time	Relative to SK	4.5V $\leq V_{CC} \leq 5.5\text{V}$	100			
			2.7V $\leq V_{CC} \leq 5.5\text{V}$	100			
			1.8V $\leq V_{CC} \leq 5.5\text{V}$	400			ns
t_{CSH}	CS Hold Time	Relative to SK		0			ns
t_{DIH}	DI Hold Time	Relative to SK	4.5V $\leq V_{CC} \leq 5.5\text{V}$	100			
			2.7V $\leq V_{CC} \leq 5.5\text{V}$	100			
			1.8V $\leq V_{CC} \leq 5.5\text{V}$	400			ns
t_{PD1}	Output Delay to "1"	AC Test	4.5V $\leq V_{CC} \leq 5.5\text{V}$			250	
			2.7V $\leq V_{CC} \leq 5.5\text{V}$			250	
			1.8V $\leq V_{CC} \leq 5.5\text{V}$			1000	
t_{PD0}	Output Delay to "0"	AC Test	4.5V $\leq V_{CC} \leq 5.5\text{V}$			250	
			2.7V $\leq V_{CC} \leq 5.5\text{V}$			250	
			1.8V $\leq V_{CC} \leq 5.5\text{V}$			1000	
t_{SV}	CS to Status Valid	AC Test	4.5V $\leq V_{CC} \leq 5.5\text{V}$			250	
			2.7V $\leq V_{CC} \leq 5.5\text{V}$			250	
			1.8V $\leq V_{CC} \leq 5.5\text{V}$			1000	
t_{DF}	CS to DO in High Impedance	AC Test $CS = V_{IL}$	4.5V $\leq V_{CC} \leq 5.5\text{V}$			100	
			2.7V $\leq V_{CC} \leq 5.5\text{V}$			150	
			1.8V $\leq V_{CC} \leq 5.5\text{V}$			400	
t_{WP}	Write Cycle Time			0.1	3	10	ms
Endurance ⁽¹⁾	5.0V, 25°C			1M			Write Cycle

Note: 1. This parameter is characterized and is not 100% tested.

3. Functional Description

The AT93C46A is accessed via a simple and versatile three-wire serial communication interface. Device operation is controlled by seven instructions issued by the host processor. **A valid instruction starts with a rising edge of CS** and consists of a start bit (logic “1”) followed by the appropriate op code and the desired memory address location.

Table 3-1. Instruction Set for the AT93C46A

Instruction	SB	Op Code	Address	Comments
			x 16	
READ	1	10	$A_5 - A_0$	Reads data stored in memory, at specified address
EWEN	1	00	11XXXX	Write enable must precede all programming modes
ERASE	1	11	$A_5 - A_0$	Erase memory location $A_n - A_0$
WRITE	1	01	$A_5 - A_0$	Writes memory location $A_n - A_0$
ERAL	1	00	10XXXX	Erases all memory locations. Valid only at $V_{CC} = 4.5V$ to $5.5V$
WRAL	1	00	01XXXX	Writes all memory locations. Valid only at $V_{CC} = 4.5V$ to $5.5V$
EWDS	1	00	00XXXX	Disables all programming instructions

READ (READ): The Read (READ) instruction contains the address code for the memory location to be read. After the instruction and address are decoded, data from the selected memory location is available at the serial output pin DO. Output data changes are synchronized with the rising edges of serial clock SK. It should be noted that a dummy bit (logic “0”) precedes the 16-bit data output string.

ERASE/WRITE ENABLE (EWEN): To assure data integrity, the part automatically goes into the Erase/Write Disable (EWDS) state when power is first applied. An Erase/Write Enable (EWEN) instruction must be executed first before any programming instructions can be carried out. Please note that once in the EWEN state, programming remains enabled until an EWDS instruction is executed or V_{CC} power is removed from the part.

ERASE (ERASE): The Erase (ERASE) instruction programs all bits in the specified memory location to the logical “1” state. The self-timed erase cycle starts once the Erase instruction and address are decoded. The DO pin outputs the ready/busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (t_{CS}). A logic “1” at pin DO indicates that the selected memory location has been erased and the part is ready for another instruction.

WRITE (WRITE): The Write (WRITE) instruction contains the 16 bits of data to be written into the specified memory location. The self-timed programming cycle, t_{WP} , starts after the last bit of data is received at serial data input pin DI. The DO pin outputs the ready/busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (t_{CS}). A logic “0” at DO indicates that programming is still in progress. A logic “1” indicates that the memory location at the specified address has been written with the data pattern contained in the instruction and the part is ready for further instructions. **A ready/busy status cannot be obtained if the CS is brought high after the end of the self-timed programming cycle, t_{WP}**

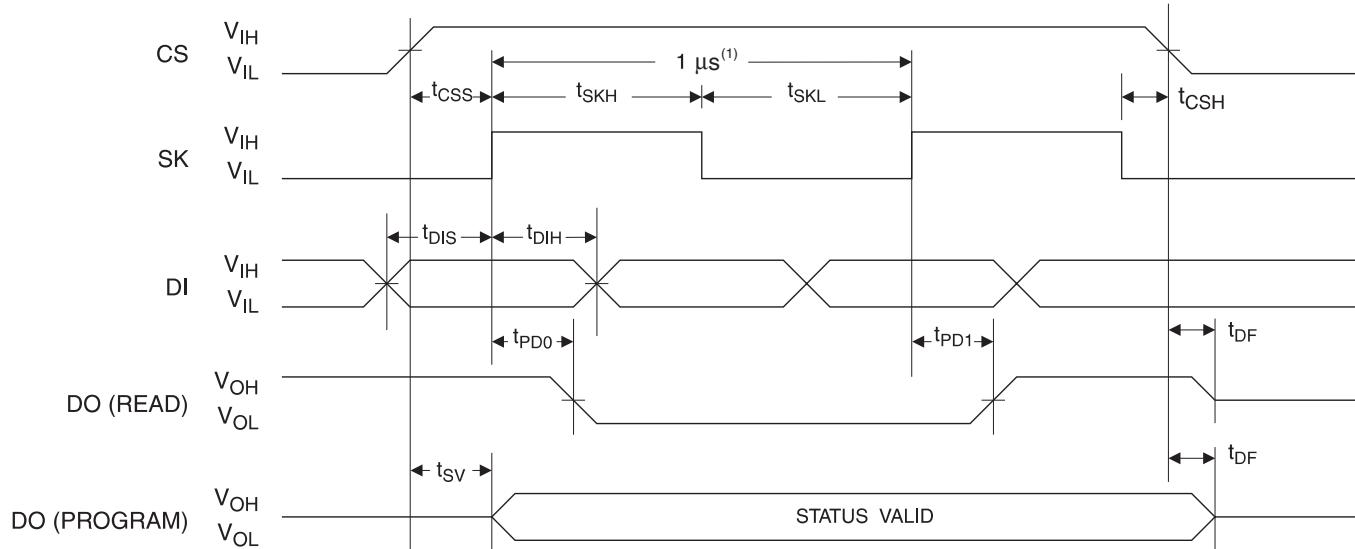
ERASE ALL (ERAL): The Erase All (ERAL) instruction programs every bit in the memory array to the logic “1” state and is primarily used for testing purposes. The DO pin outputs the ready/busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (t_{CS}). The ERAL instruction is valid only at $V_{CC} = 5.0V \pm 10\%$.

WRITE ALL (WRAL): The Write All (WRAL) instruction programs all memory locations with the data patterns specified in the instruction. The DO pin outputs the ready/busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (t_{CS}). The WRAL instruction is valid only at $V_{CC} = 5.0V \pm 10\%$.

ERASE/WRITE DISABLE (EWDS): To protect against accidental data disturb, the Erase/Write Disable (EWDS) instruction disables all programming modes and should be executed after all programming operations. The operation of the Read instruction is independent of both the EWEN and EWDS instructions and can be executed at any time.

4. Timing Diagrams

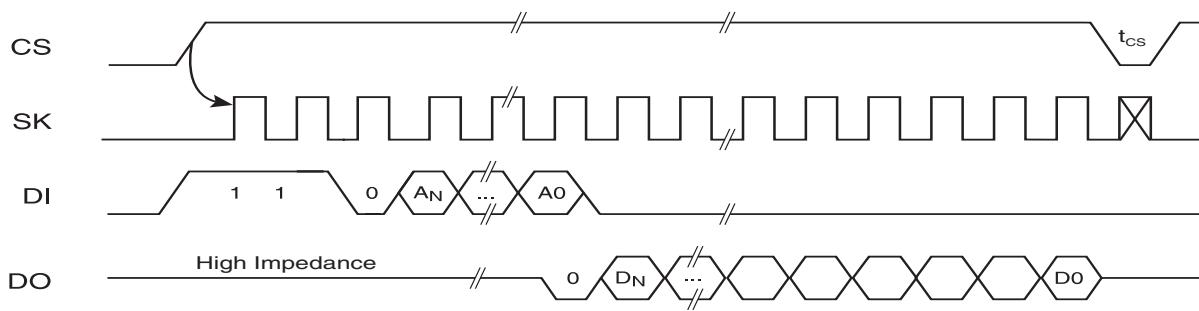
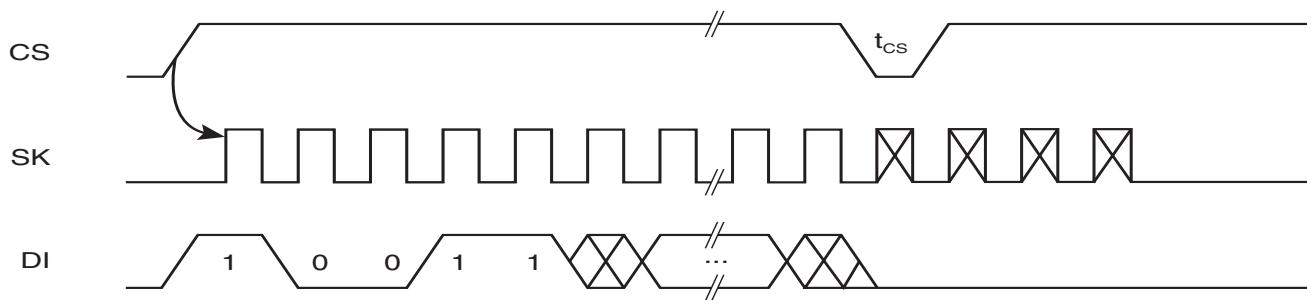
Figure 4-1. Synchronous Data Timing



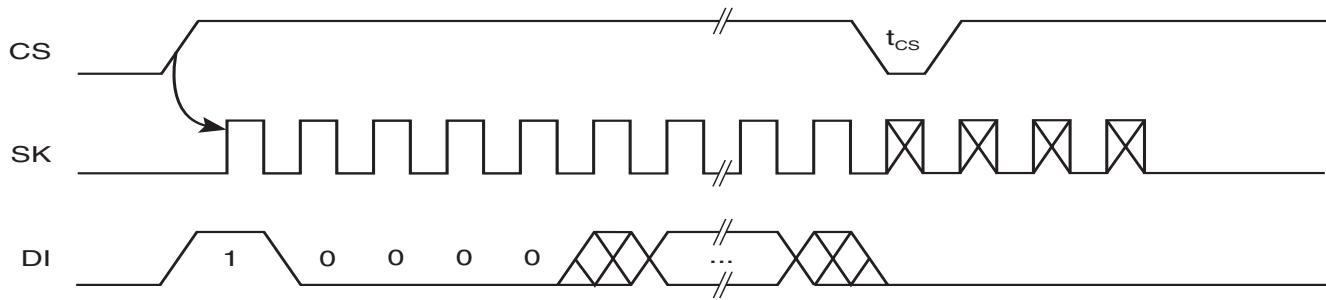
Note: 1. This is the minimum SK period.

Table 4-1. Organization Key for Timing Diagrams

I/O	AT93C46A
	$\times 16$
A_N	A_5
D_N	D_{15}

Figure 4-2. READ Timing**Figure 4-3.** EWEN Timing⁽¹⁾

Note: 1. Requires a minimum of nine clock cycles.

Figure 4-4. EWDS Timing⁽¹⁾

Note: 1. Requires a minimum of nine clock cycles.

Figure 4-5. WRITE Timing

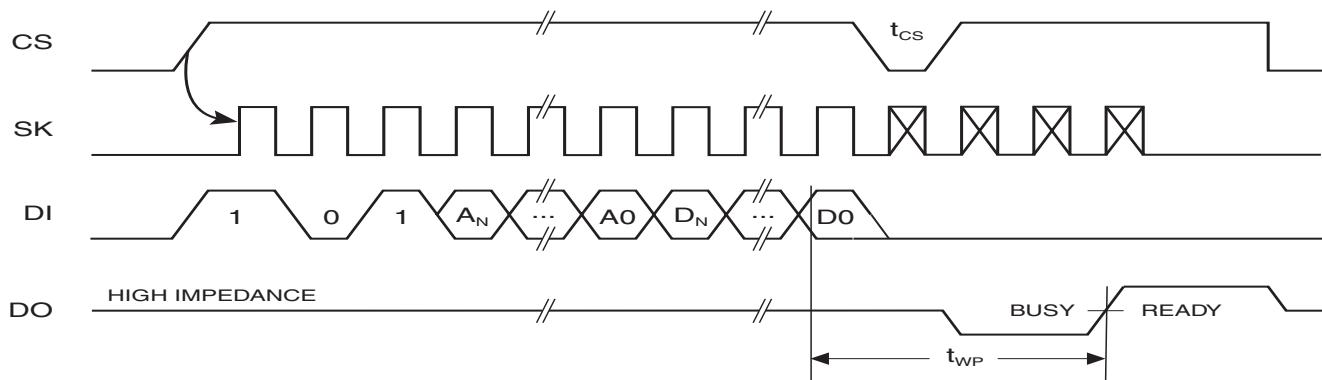
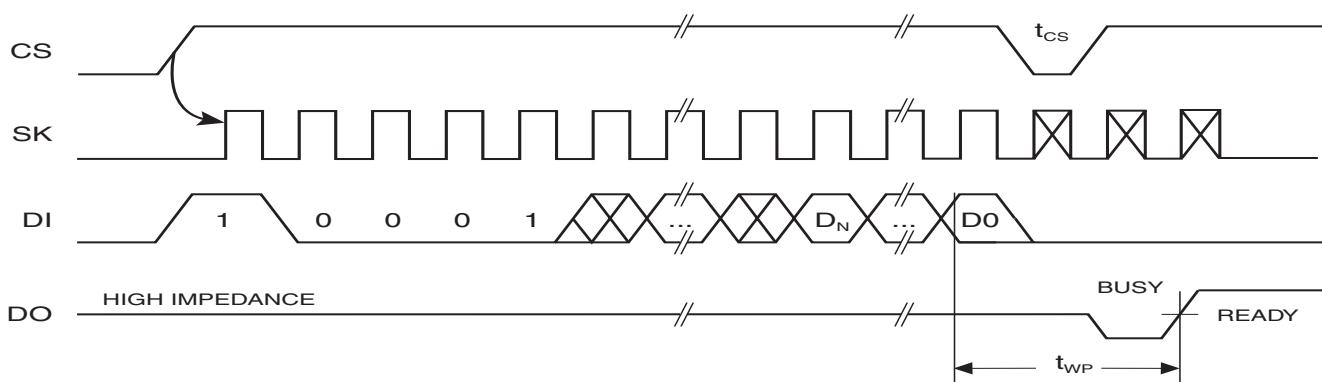


Figure 4-6. WRAL Timing^{(1),(2)}



Notes:

1. Valid only at $V_{CC} = 4.5V$ to $5.5V$.
2. Requires a minimum of nine clock cycles.

Figure 4-7. ERASE Timing

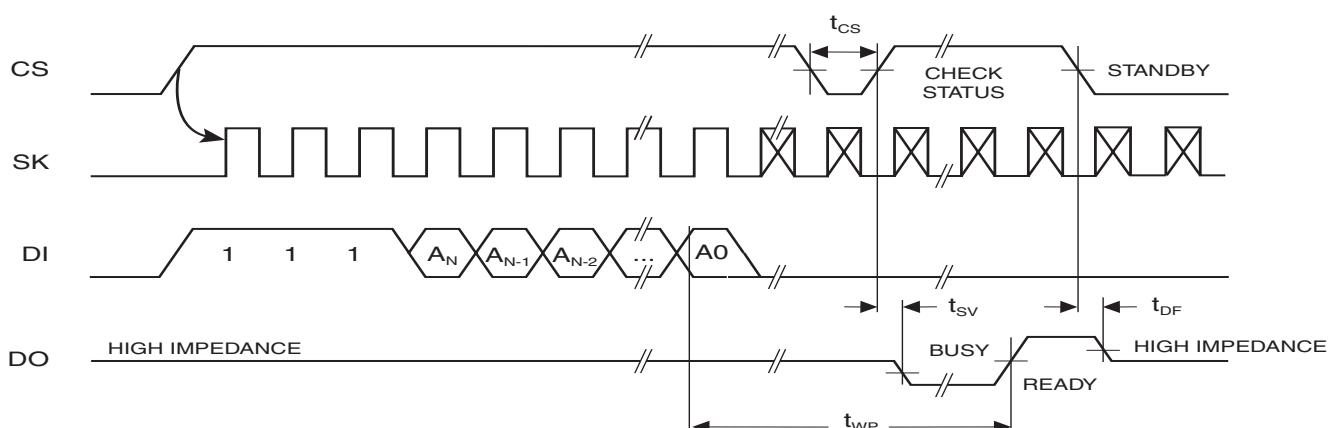
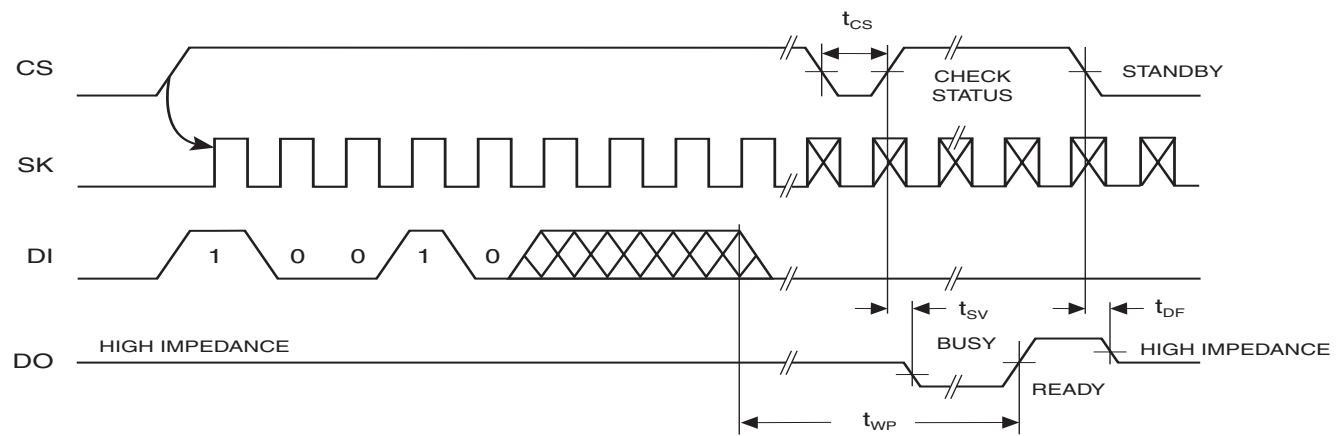


Figure 4-8. ERAL Timing⁽¹⁾

Note: 1. Valid only at $V_{CC} = 4.5V$ to $5.5V$.

Ordering Information⁽¹⁾

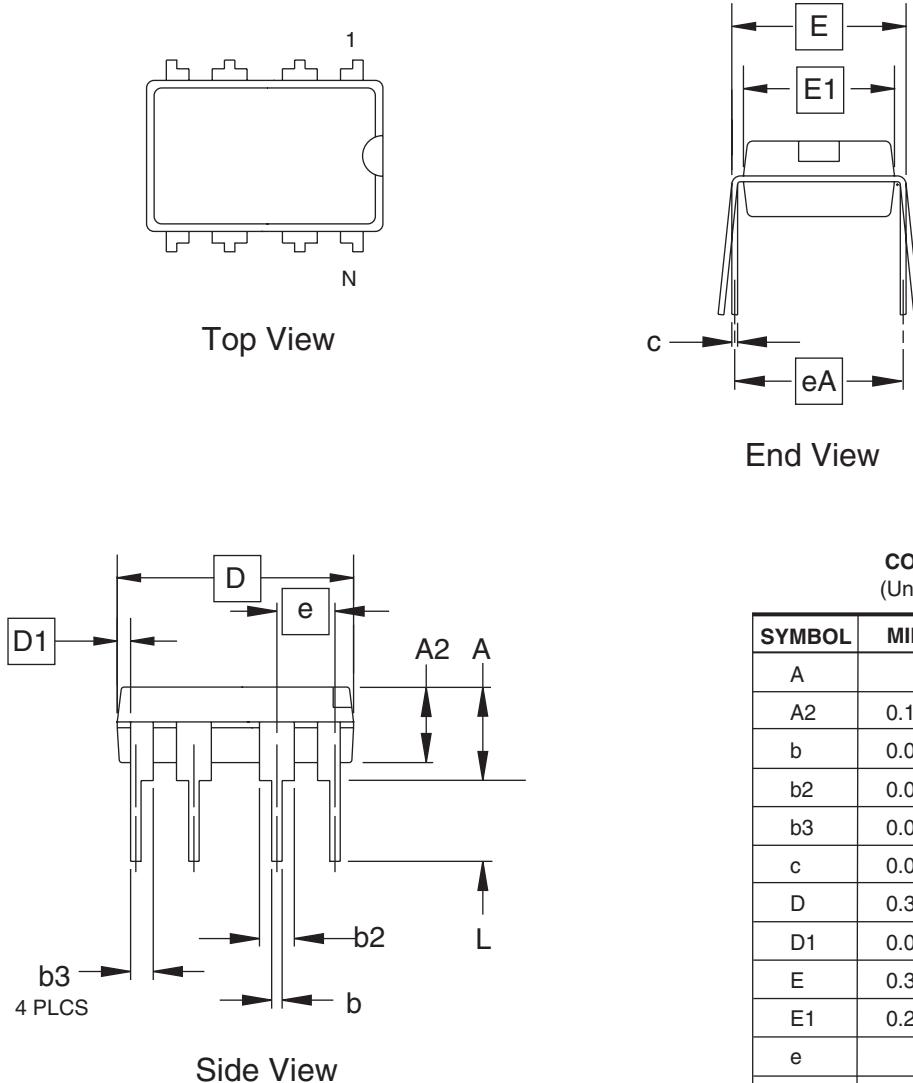
Ordering Code	Package	Operation Range
AT93C46A-10PU-2.7	8P3	
AT93C46A-10PU-1.8	8P3	
AT93C46A-10SU-2.7	8S1	Lead-free/Halogen-free/ Industrial Temperature (-40°C to 85°C)
AT93C46A-10SU-1.8	8S1	
AT93C46A-10TU-2.7	8A2	
AT93C46A-10TU-1.8	8A2	

Notes: 1. For 2.7V devices used in the 4.5V to 5.5V range, please refer to performance values in [Table 2-3 on page 3](#) and [Table 2-4 on page 4](#). Not recommended for new design. Please see AT93C46E datasheet.

Package Type	
8P3	8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)
8S1	8-lead, 0.150" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC)
8A2	8-lead, 0.170" Wide, Thin Small Outline Package (TSSOP)
Options	
-2.7	Low Voltage (2.7V to 5.5V)
-1.8	Low Voltage (1.8V to 5.5V)

5. Packaging Information

5.1 8P3 – PDIP



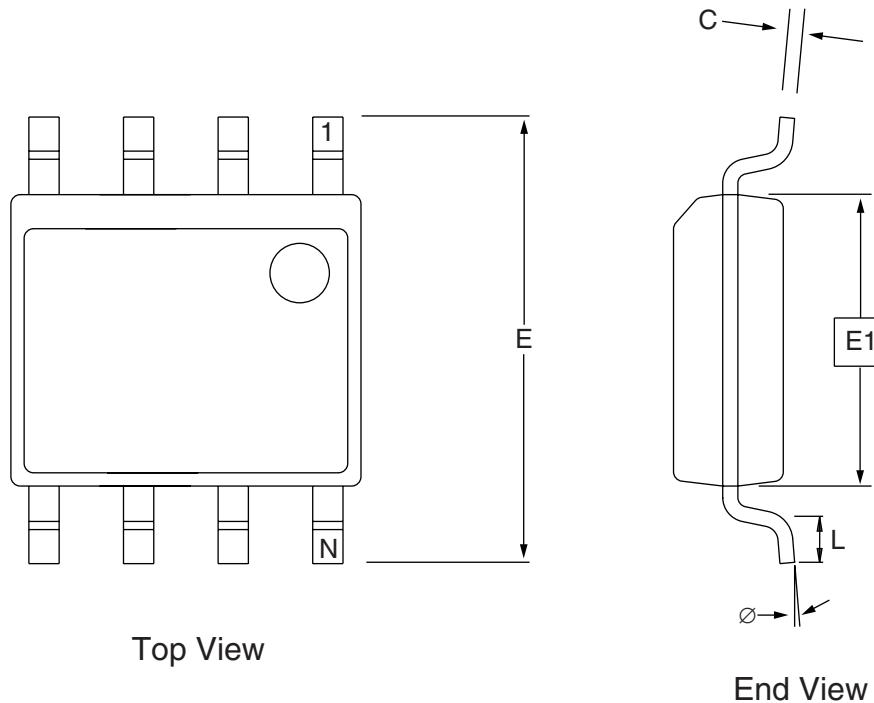
Notes:

1. This drawing is for general information only; refer to JEDEC Drawing MS-001, Variation BA for additional information.
2. Dimensions A and L are measured with the package seated in JEDEC seating plane Gauge GS-3.
3. D, D1 and E1 dimensions do not include mold Flash or protrusions. Mold Flash or protrusions shall not exceed 0.010 inch.
4. E and eA measured with the leads constrained to be perpendicular to datum.
5. Pointed or rounded lead tips are preferred to ease insertion.
6. b2 and b3 maximum dimensions do not include Dambar protrusions. Dambar protrusions shall not exceed 0.010 (0.25 mm).

01/09/02

ATMEL	2325 Orchard Parkway San Jose, CA 95131	TITLE 8P3, 8-lead, 0.300" Wide Body, Plastic Dual In-line Package (PDIP)	DRAWING NO.	REV.
			8P3	B

5.2 8S1 – JEDEC SOIC



COMMON DIMENSIONS
(Unit of Measure = mm)

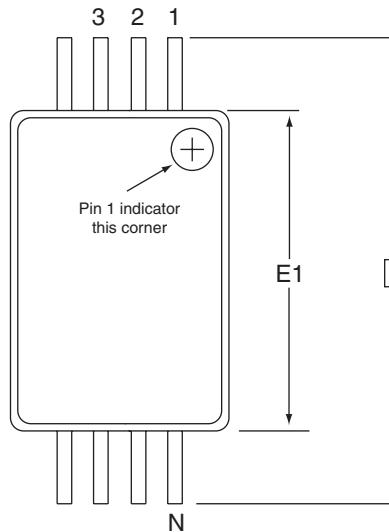
SYMBOL	MIN	NOM	MAX	NOTE
A	1.35	—	1.75	
A1	0.10	—	0.25	
b	0.31	—	0.51	
C	0.17	—	0.25	
D	4.80	—	5.00	
E1	3.81	—	3.99	
E	5.79	—	6.20	
e	1.27 BSC			
L	0.40	—	1.27	
Ø	0°	—	8°	

Note: These drawings are for general information only. Refer to JEDEC Drawing MS-012, Variation AA for proper dimensions, tolerances, datums, etc.

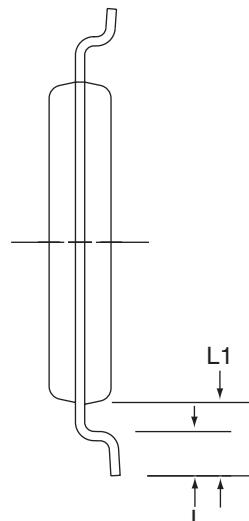
10/7/03

 1150 E. Cheyenne Mtn. Blvd. Colorado Springs, CO 80906	TITLE 8S1, 8-lead (0.150" Wide Body), Plastic Gull Wing Small Outline (JEDEC SOIC)	DRAWING NO. 8S1	REV. B
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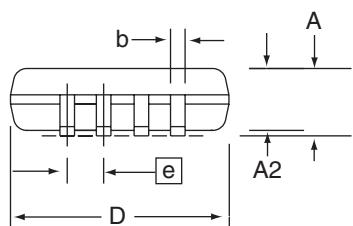
5.3 8A2 – TSSOP



Top View



End View



Side View

COMMON DIMENSIONS
 (Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
D	2.90	3.00	3.10	2, 5
E		6.40 BSC		
E1	4.30	4.40	4.50	3, 5
A	–	–	1.20	
A2	0.80	1.00	1.05	
b	0.19	–	0.30	4
e		0.65 BSC		
L	0.45	0.60	0.75	
L1		1.00 REF		

Notes:

1. This drawing is for general information only. Refer to JEDEC Drawing MO-153, Variation AA, for proper dimensions, tolerances, datums, etc.
2. Dimension D does not include mold Flash, protrusions or gate burrs. Mold Flash, protrusions and gate burrs shall not exceed 0.15 mm (0.006 in) per side.
3. Dimension E1 does not include inter-lead Flash or protrusions. Inter-lead Flash and protrusions shall not exceed 0.25 mm (0.010 in) per side.
4. Dimension b does not include Dambar protrusion. Allowable Dambar protrusion shall be 0.08 mm total in excess of the b dimension at maximum material condition. Dambar cannot be located on the lower radius of the foot. Minimum space between protrusion and adjacent lead is 0.07 mm.
5. Dimension D and E1 to be determined at Datum Plane H.

5/30/02

ATMEL	2325 Orchard Parkway San Jose, CA 95131	TITLE 8A2, 8-lead, 4.4 mm Body, Plastic Thin Shrink Small Outline Package (TSSOP)	DRAWING NO.	REV.
			8A2	B

Revision History

Doc. Rev.	Date	Comments
0539L	11/2007	Modified 'max' values on DC/AC Characteristics tables.
0539K	2/2007	Implemented revision history. Added Note to page 1 and ordering information; Not recommended for new design; please refer to AT93C46E datasheet.



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